

**• Product Summary**

Part #	V <sub>DS</sub>	R <sub>DS(on).typ</sub> (@V <sub>GS</sub> =10V)	R <sub>DS(on).typ</sub> (@V <sub>GS</sub> =4.5V)	I <sub>D</sub>
EFM2319	-40V	65mΩ	80mΩ	-5A

**• Features**

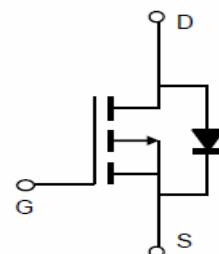
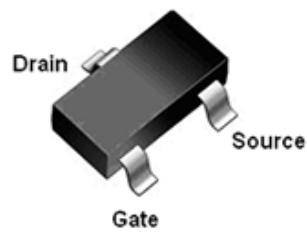
- Low R<sub>DS(on)</sub> @ V<sub>GS</sub>=-10V
- -5V Logic Level Control
- P Channel SOT23 Package
- Pb-Free, RoHS Compliant

**• Application**

- High-side Load Switch
- Switching Circuits
- High Speed line Driver

**• Ordering Information:**

Part NO.	EFM2319
Marking	2319
Packing Information	REEL TAPE
Basic ordering unit (pcs)	3000


**P-Channel MOSFET**

**SOT- 23**
**HF**
**• Absolute Maximum Ratings (T<sub>C</sub>=25°C)**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-40	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	-5	A
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	-8	A
Maximum Power Dissipation	P <sub>D</sub>	1	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 To 150	°C

**• Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>θJA</sub>	125	°C/W
--	------------------	-----	------

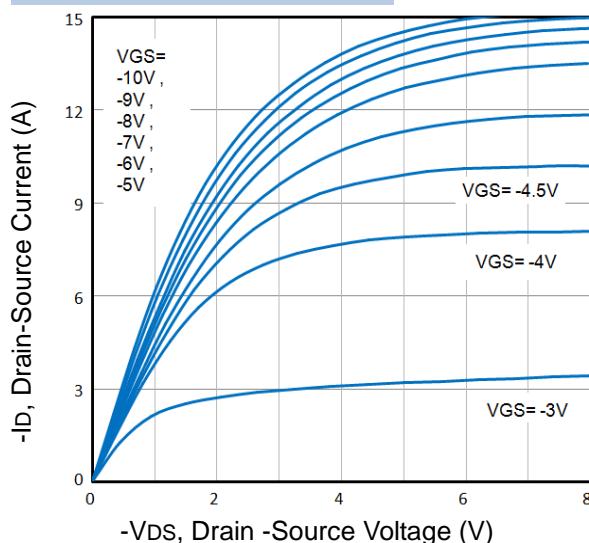
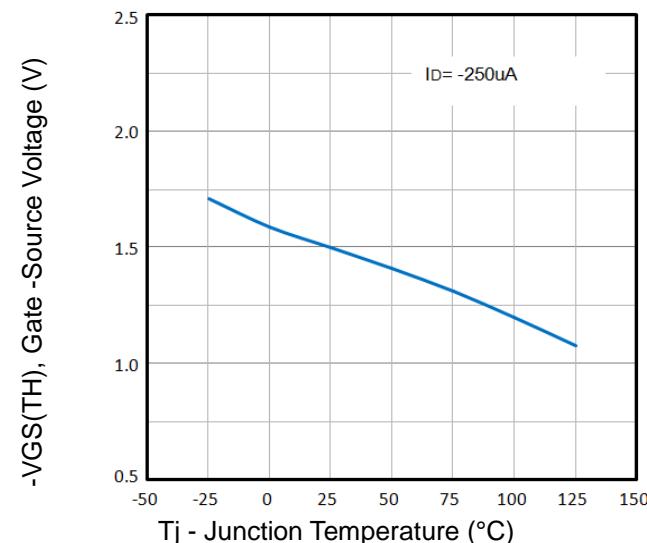
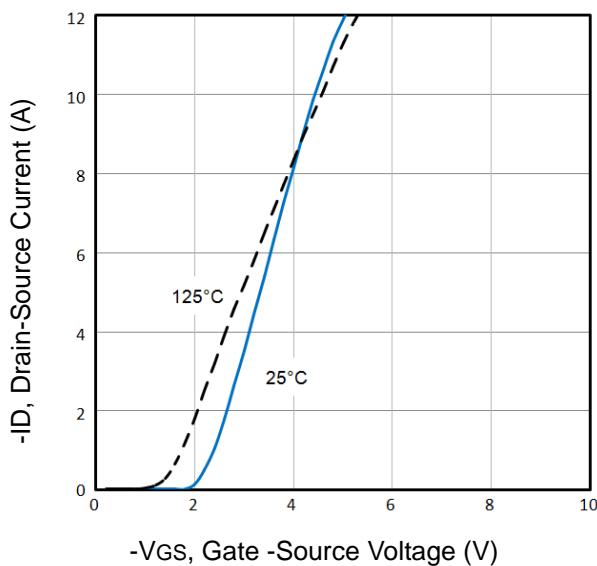
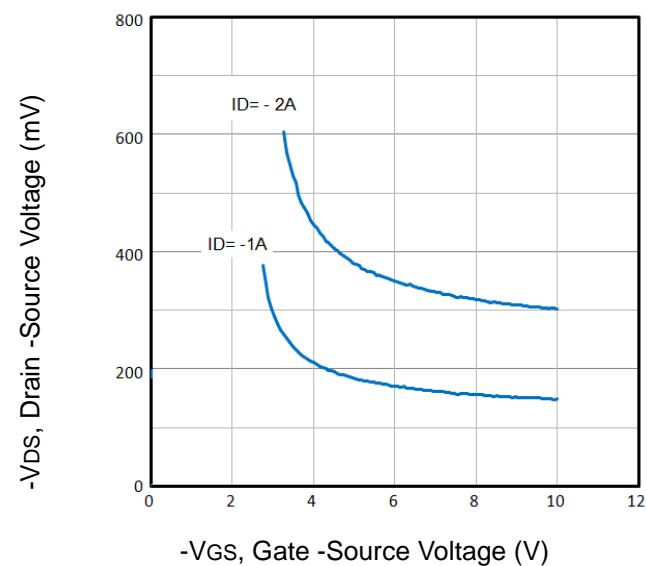
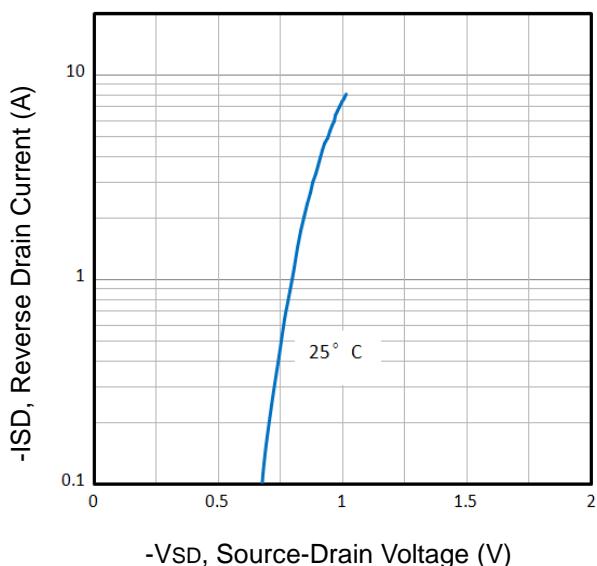
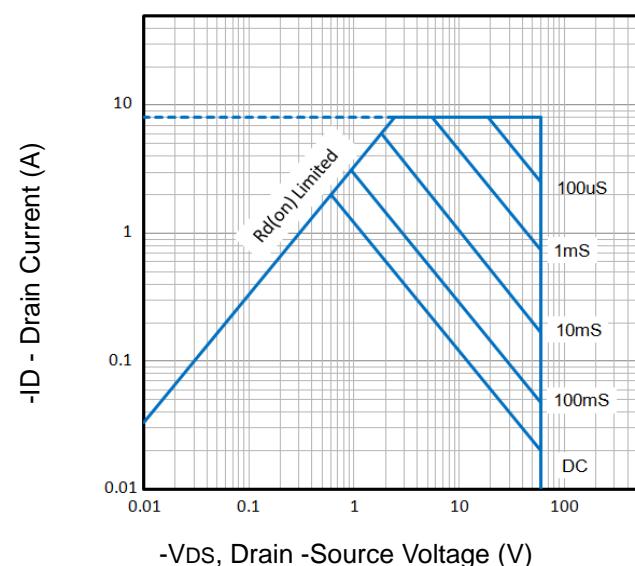
**• Static Electrical Characteristics @  $T_J = 25^\circ C$  (unless otherwise stated)**

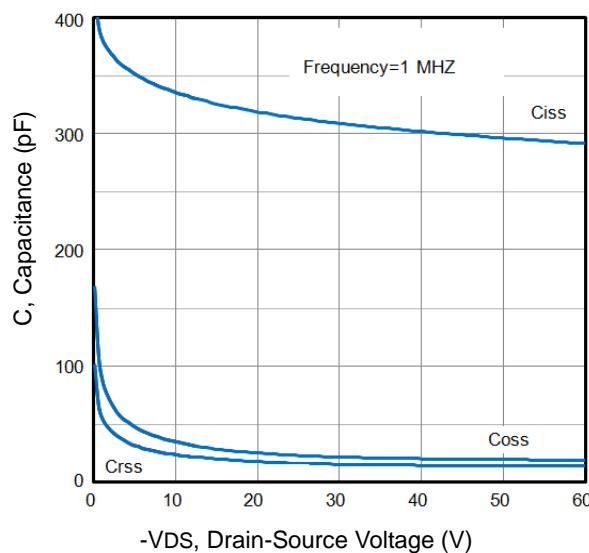
Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{DSS}$	$V_{GS}=0V I_D=250\mu A$	-40	--	--	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-40V V_{GS}=0V$	--	--	-1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V V_{DS}=0V$	--	--	$\pm 100$	nA
<b>On Characteristics</b> <small>(Note 3)</small>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS} I_D=250\mu A$	-1.0	-1.6	-2.5	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=-10V I_D=5A$	--	65	80	$m\Omega$
		$V_{GS}=-4.5V I_D=4A$	--	80	110	$m\Omega$
<b>Dynamic Characteristics</b> <small>(Note 4)</small>						
Input Capacitance	$C_{iss}$	$V_{DS}=-40V V_{GS}=0V$ $F=1.0MHz$	--	310	--	PF
Output Capacitance	$C_{oss}$		--	22	--	PF
Reverse Transfer Capacitance	$C_{rss}$		--	15	--	PF
<b>Switching Characteristics</b> <small>(Note 4)</small>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=-40V I_D=-5A$ $V_{GS}=-10V R_G=3.3\Omega$	--	41	--	nS
Turn-on Rise Time	$t_r$		--	22	--	nS
Turn-Off Delay Time	$t_{d(off)}$		--	25	--	nS
Turn-Off Fall Time	$t_f$		--	32	--	nS
Total Gate Charge	$Q_g$	$V_{DS}=-40V I_D=-5A$ $V_{GS}=-10V$	--	5.4	--	nC
Gate-Source Charge	$Q_{gs}$		--	1.1	--	nC
Gate-Drain Charge	$Q_{gd}$		--	1.6	--	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <small>(Note 3)</small>	$V_{SD}$	$V_{GS}=0V I_S=-5A$	--	-0.84	-1.2	V
Diode Forward Current <small>(Note 2)</small>	$I_S$		--	--	-3.4	A

**Notes:**

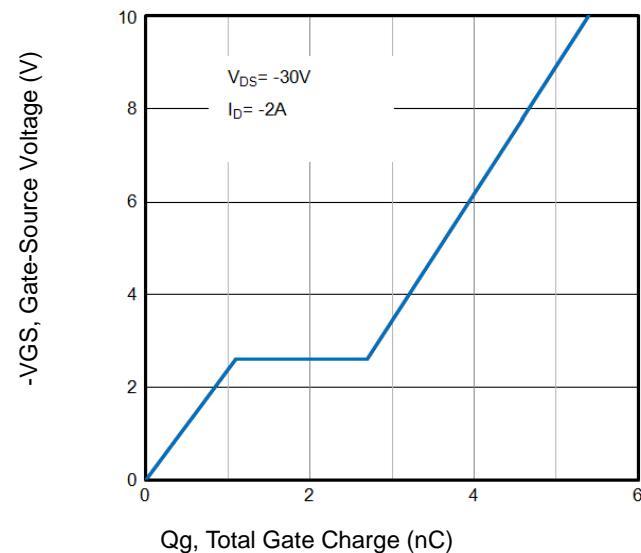
① Pulse width limited by maximum allowable junction temperature

② Pulse test ; Pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .

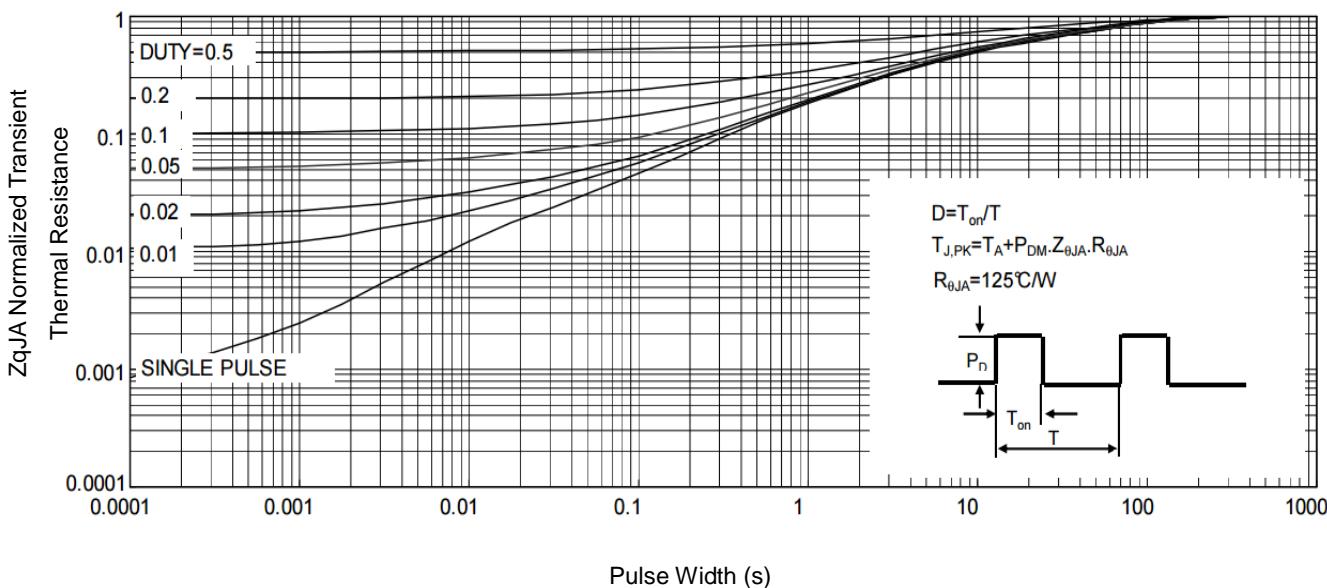
**• Typical Characteristics**

**Fig1.** Typical Output Characteristics

**Fig2.** Normalized Threshold Voltage Vs. Temperature

**Fig3.** Typical Transfer Characteristics

**Fig4.** Drain -Source Voltage vs Gate -Source Voltage

**Fig5.** Typical Source-Drain Diode Forward Voltage

**Fig6.** Maximum Safe Operating Area



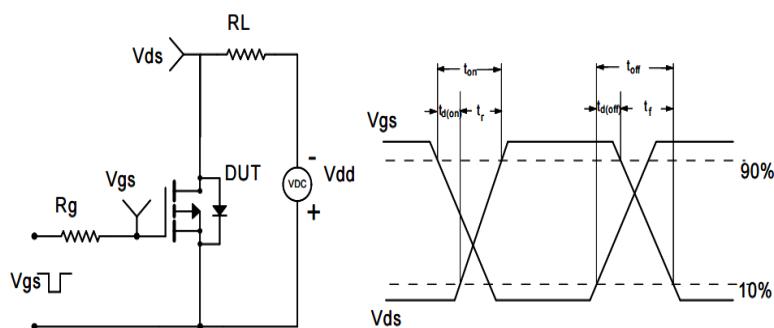
**Fig7.** Typical Capacitance Vs. Drain-Source Voltage



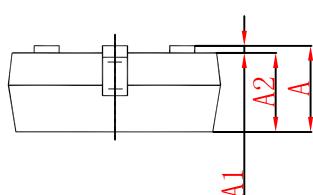
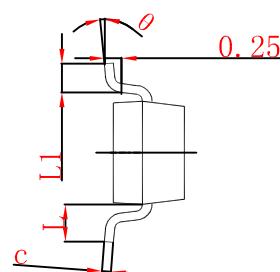
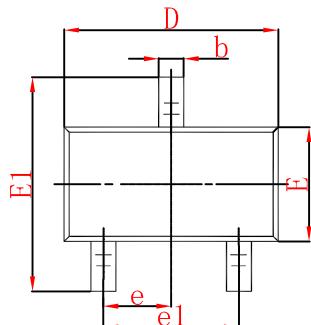
**Fig8.** Typical Gate Charge Vs. Gate-Source Voltage



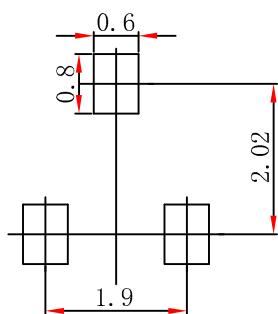
**Fig9.** Normalized Maximum Transient Thermal Impedance



**Fig10.** Switching Time Test Circuit and waveforms

**SOT-23 Package Outline Dimensions**


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°


**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.